

Quantum Hall Effect

Marcello Porta



YRS Geneva 2021

Transport in condensed matter

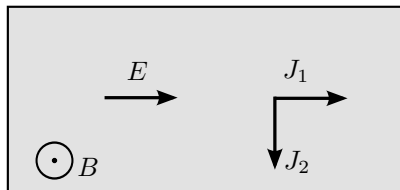
- Endless source of beautiful mathematical problems, combining **different mathematical methods** (analysis, probability, geometry...)
- Loosely speaking: understand how an electron gas, formed by a large number of particles, responds to **external perturbations** (e.g.: external electric field, variation of chemical potential, etc).
- The motion of the individual charge carriers is described by the **Schrödinger equation**. For one particle with wave function $\psi \in L^2(\mathbb{R}^d)$:

$$i\partial_t\psi_t = H\psi_t, \quad H = H^* = \text{Hamiltonian}, \quad \psi_0 = \psi.$$

We will be interested in systems formed by **∞ -many particles**. In some cases, quantum mechanical effects remain visible at a **macroscopic scale**.

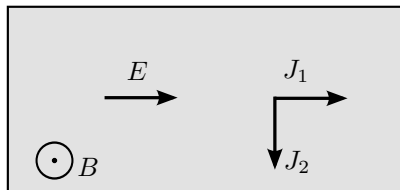
The Hall effect - Edwin Hall 1879

- **Setting:** Ultrathin materials exposed to **transverse magnetic field** B and a weak in-plane **electric field** E .



The Hall effect - Edwin Hall 1879

- **Setting:** Ultrathin materials exposed to **transverse magnetic field** B and a weak in-plane **electric field** E .



- **Linear response** (weak E):

$$J_1 = \sigma_{11}E, \quad J_2 = \sigma_{21}E$$

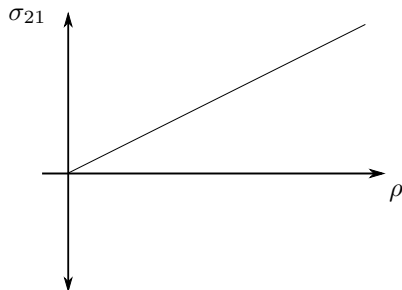
σ_{11} = longitudinal conductivity, $\sigma_{21} = -\sigma_{12}$ = **Hall conductivity**.

From the laws of **classical electrodynamics**:

$$\sigma_{21} = \frac{e^2}{h}\nu, \quad \nu = \frac{\rho}{|e|\frac{B}{hc}} \quad (\rho = \text{density of charge carriers})$$

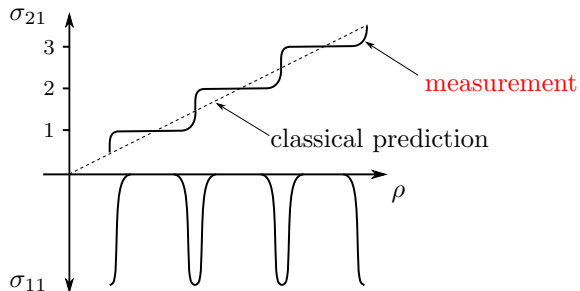
The Hall effect

- **Classical prediction:** linear behavior of transverse conductivity



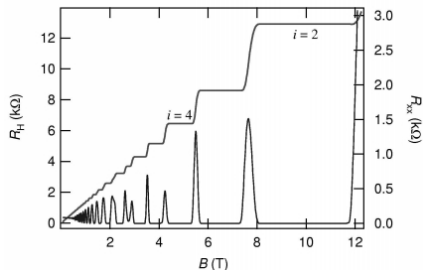
The Hall effect

- von Klitzing '80. Experiment on GaAs-heterostructures (insulators).
Large magnetic field B and small temperature T .



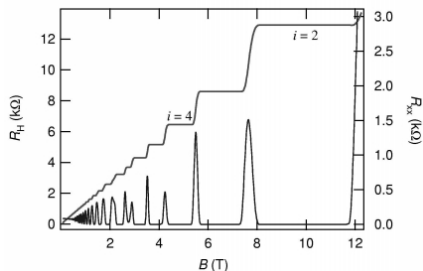
The Hall effect

- von Klitzing '80. Experiment on GaAs-heterostructures (insulators).
Large magnetic field B and small temperature T ($\sim 0.1K$).



The Hall effect

- von Klitzing '80. Experiment on GaAs-heterostructures (insulators). Large magnetic field B and small temperature T ($\sim 0.1K$).



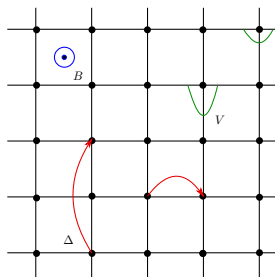
- Integer Quantum Hall effect: σ_{21} is quantized, with 10^{-9} precision!

$$\sigma_{21} = \frac{e^2}{h} n, \quad n \in \mathbb{Z}.$$

Purely quantum phenomenon. First example of topological insulator.

Theory: setting

- Electron gas on an infinite $2d$ lattice as a model for a crystal, in the tight-binding approximation. E.g.: \mathbb{Z}^2 .



where:

- Δ : lattice hopping (e.g.: lattice Laplacian);
- V : external potential (periodic potential, impurities...)
- B : constant magnetic field.

Theory: setting

- Example of **single-particle Hamiltonian**, on $\ell^2(\mathbb{Z}^2)$:

$$H = -\Delta_A + V, \quad (V\psi)(x) = V(x)\psi(x)$$

where A is a vector potential generating the magnetic field:

$$\Delta_A(x; y) = \Delta(x; y) e^{i \int_{x \rightarrow y} d\ell \cdot A(\ell)}, \quad \int_{\partial(\text{plaquette})} d\ell \cdot A(\ell) = \text{Flux}(B)$$

Theory: setting

- Example of **single-particle Hamiltonian**, on $\ell^2(\mathbb{Z}^2)$:

$$H = -\Delta_A + V, \quad (V\psi)(x) = V(x)\psi(x)$$

where A is a vector potential generating the magnetic field:

$$\Delta_A(x; y) = \Delta(x; y) e^{i \int_{x \rightarrow y} d\ell \cdot A(\ell)}, \quad \int_{\partial(\text{plaquette})} d\ell \cdot A(\ell) = \text{Flux}(B)$$

- **Ground state** of many, noninteracting fermions: “fill the Fermi sea”, up to the Fermi energy μ . **Averages of observables**, $O = O^*$:

$$\langle O \rangle_\mu := \text{Tr}_{\ell^2(\mathbb{Z}^2)} O P_\mu, \quad P_\mu = \chi(H \leq \mu) = \text{Fermi projector.}$$

Theory: setting

- Example of **single-particle Hamiltonian**, on $\ell^2(\mathbb{Z}^2)$:

$$H = -\Delta_A + V, \quad (V\psi)(x) = V(x)\psi(x)$$

where A is a vector potential generating the magnetic field:

$$\Delta_A(x; y) = \Delta(x; y) e^{i \int_{x \rightarrow y} d\ell \cdot A(\ell)}, \quad \int_{\partial(\text{plaquette})} d\ell \cdot A(\ell) = \text{Flux}(B)$$

- **Ground state** of many, noninteracting fermions: “fill the Fermi sea”, up to the Fermi energy μ . **Averages of observables**, $O = O^*$:

$$\langle O \rangle_\mu := \text{Tr}_{\ell^2(\mathbb{Z}^2)} O P_\mu, \quad P_\mu = \chi(H \leq \mu) = \text{Fermi projector.}$$

- Important assumption: **insulating behavior**,

$$|\langle \delta_x, P_\mu \delta_y \rangle| \leq C e^{-c|x-y|}.$$

True if $\mu \notin \sigma(H)$ (spectral gap), or if $\mu \in$ **mobility gap** (later).

Linear response

- **Time-dependent perturbation**, for $t \leq 0$ ($\eta \geq 0$ small):

$$A(\ell) \rightarrow A(\ell) + a(\eta t), \quad \partial_t a(\eta t) =: E(t), \quad a(-\infty) = 0,$$

nontrivial **time evolution**:

$$i\partial_t P(t) = [H(t), P(t)], \quad P(-\infty) = P_\mu.$$

Linear response

- **Time-dependent perturbation**, for $t \leq 0$ ($\eta \geq 0$ small):

$$A(\ell) \rightarrow A(\ell) + a(\eta t), \quad \partial_t a(\eta t) =: E(t), \quad a(-\infty) = 0,$$

nontrivial **time evolution**:

$$i\partial_t P(t) = [H(t), P(t)], \quad P(-\infty) = P_\mu.$$

- The **final goal** is to understand the E -dependence of:

$$\mathcal{J} = \lim_{L \rightarrow \infty} \frac{1}{|\Lambda_L|} \text{Tr} \chi(x \in \Lambda_L) J P(0)$$

with $J = i[H, X] =$ **current operator**, as $E \rightarrow 0$.

Linear response

- **Time-dependent perturbation**, for $t \leq 0$ ($\eta \geq 0$ small):

$$A(\ell) \rightarrow A(\ell) + a(\eta t), \quad \partial_t a(\eta t) =: E(t), \quad a(-\infty) = 0,$$

nontrivial **time evolution**:

$$i\partial_t P(t) = [H(t), P(t)], \quad P(-\infty) = P_\mu.$$

- The **final goal** is to understand the E -dependence of:

$$\mathcal{J} = \lim_{L \rightarrow \infty} \frac{1}{|\Lambda_L|} \text{Tr} \chi(x \in \Lambda_L) J P(0)$$

with $J = i[H, X] =$ **current operator**, as $E \rightarrow 0$.

- **Linear response**: expand the state in E ,

$$\mathcal{J} = \sigma E + o(E), \quad E \equiv E(0),$$

where $\sigma =$ conductivity matrix, given by **Kubo formula**:

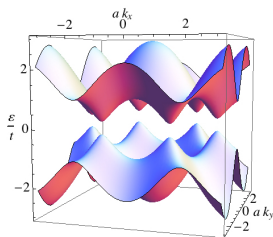
$$\sigma_{ij} = \lim_{L \rightarrow \infty} \frac{i}{|\Lambda_L|} \text{Tr} \chi(x \in \Lambda_L) P_\mu [[P_\mu, X_i], [P_\mu, X_j]].$$

Gapped systems

- Let H on $\ell^2(\mathbb{Z}^2; \mathbb{C}^M)$, **translation invariant**: $H(x; y) \equiv H(x - y)$.
Bloch Hamiltonian: $\hat{H}(k)$, with $k \in \mathbb{T}^2$. Eigenvalue equation:

$$\hat{H}(k)\varphi_i(k) = \varepsilon_i(k)\varphi_i(k), \quad i = 1, \dots, M,$$

where $\varepsilon_i(k)$ define the **energy bands**. Suppose μ is in a **spectral gap**.



Gapped systems

- Let H on $\ell^2(\mathbb{Z}^2; \mathbb{C}^M)$, **translation invariant**: $H(x; y) \equiv H(x - y)$.
Bloch Hamiltonian: $\hat{H}(k)$, with $k \in \mathbb{T}^2$. Eigenvalue equation:

$$\hat{H}(k)\varphi_i(k) = \varepsilon_i(k)\varphi_i(k), \quad i = 1, \dots, M,$$

where $\varepsilon_i(k)$ define the **energy bands**. Suppose μ is in a **spectral gap**.

- Let $P_\mu = \bigoplus_{k \in \mathbb{T}^2} \hat{P}(k)$ and suppose $\hat{P}(k) = |\varphi_1(k)\rangle\langle\varphi_1(k)|$. Then:

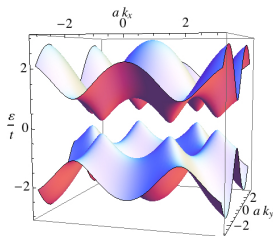
$$\sigma_{12} = \int_{\mathbb{T}^2} \frac{dk}{(2\pi)^2} \vec{\nabla} \times \langle \varphi_1(k), i\vec{\nabla}_k \varphi_1(k) \rangle \in \frac{1}{2\pi} \mathbb{Z}$$

- More generally, $\sigma_{12} =$ **Chern number** of Bloch bundle,

$$\mathcal{E}_B = \{(k, u) \in \mathbb{T}^2 \times \mathbb{C}^M \mid u \in \text{Ran } \hat{P}(k)\} \quad [\text{TKNN}; \text{Avron, Seiler, Simon}]$$

Plateaux

- In the previous example we crucially used that μ lies in a **spectral gap**.
E.g.: $\varphi(k)$ eigenstate of $\hat{H}(k)$ corresponding to the lowest eigenvalue.

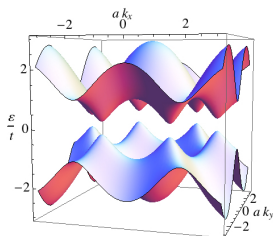


- This setting **cannot** explain the emergence of plateaux! Varying μ in the spectral gap **does not change** the density of charge carriers.

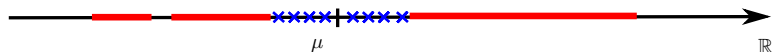


Plateaux

- In the previous example we crucially used that μ lies in a **spectral gap**.
E.g.: $\varphi(k)$ eigenstate of $\hat{H}(k)$ corresponding to the lowest eigenvalue.



- **Strong disorder:** $V(x) = \lambda\omega_x$, $|\lambda| \gg 1$, $\{\omega_x\}$ i.i.d. \Rightarrow **Anderson loc.**
For μ in a **mobility gap**: σ_{12} is integer-valued, and **continuous** in μ !



[Bellissard, van Elst, Schulz-Baldes; AS²; Aizenman, Graf]

Conclusion and open questions

- The precise explanation of the IQHE is a major achievement of mathematical physics.
- It pioneered the study of **topological insulators** and the notion of **topological phase of matter**.
- **Many-body interactions?**

In the last years, the **stability** of the IQHE against **weak** many-body interactions has been rigorously understood.

- Two major open questions:
 - Existence of **plateaux** for many-body quantum systems (many-body localization?)
 - Strong interactions should have a dramatic consequence on transport. **Fractional** quantum Hall effect:

$$\sigma_{12} \in \frac{1}{2\pi} \mathbb{Q} .$$

Proof from a microscopic model?